NSN 5961-01-465-5609

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-465-5609 **Inclosure Material:** Glass **Overall Length:** 81.280 millimeters **Terminal Length:** 5.080 millimeters **End Application:** Aircraft.F.111e/ifscm81349 **Mounting Facility Quantity: Mounting Method:** Press fit **Terminal Circle Diameter:** 2.290 millimeters **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 regulator voltage, dc **Power Rating Per Characteristic:** 500.0 milliwatts small-signal output power, common-base preset **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Test Data Document:** 81349-mil-prf-19500/117l specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.